Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
1.656 inches	
Overall Diameter:	
1.656 inches	
Function For Which Designed:	
Rectifier	
Internal Configuration:	
Junction contact	
Mounting Method:	
Press fit	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Char	racteristic:
	voltage and 600.0 repetitive peak off-state voltage and 600.0 repetitive peak reverse voltage
Current Rating Per Characteristi	ic:
1800.00 amperes peak forward su	rge current absolute
Power Rating Per Characteristic	
2.0 watts small-signal input power,	, common-collector universal
Maximum Operating Tempuratu	re Per Measurement Point:
125.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: pn	pn
Terminal Type And Quantity:	
2 tab, solder lug	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	